

PN3566

NPN General Purpose Amplifier

- This device is for use as a medium amplifier and switch requiring collector currents up 300mA.
- Sourced from process 19.



1. Emitter 2. Base 3. Collector

Absolute Maximum Ratings T_a=25°C unless otherwise noted

Symbol	Parameter	Value	Units
V _{CEO}	Collector-Emitter Voltage	30	V
V _{CBO}	Collector-Base Voltage	40	V
V _{EBO}	Emitter-Base Voltage	5	V
I _C	Collector Current - Continuous	600	mA
T _{J,} T _{STG}	Operating and Storage Junction Temperature Range	- 55 ~ 150	°C

Electrical Characteristics T_a =25°C unless otherwise noted

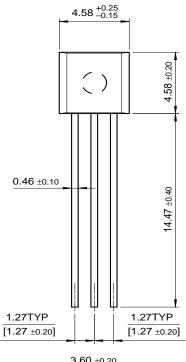
Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Units
Off Chara	Off Characteristics					
V _{(BR)CEO}	Collector-Emitter Breakdown Voltage *	$I_C = 30 \text{mA}, I_B = 0$	30			V
V _{(BR)CBO}	Collector-Base Breakdown Voltage	$I_C = 100 \mu A, I_E = 0$	40			V
V _{(BR)EBO}	Emitter-Base Breakdown Voltage	$I_E = 10\mu A, I_C = 0$	5			V
I _{CBO}	Collector Cut-off Current	$V_{CB} = 20V, I_{E} = 0$			50	nA
I _{EBO}	Emitter Cut-off Current	$V_{EB} = 5V, I_{C} = 0$			10	μΑ
On Characteristics						
h _{FE}	DC Current Gain	$V_{CE} = 10V, I_{C} = 2.0mA$	80			
		$V_{CE} = 10V, I_{C} = 10mA$	150		600	
V _{CE} (sat)	Collector-Emitter Saturation Voltage *	$I_C = 100 \text{mA}, I_B = 10 \text{mA}$			1.0	V
V _{BE} (on)	Base-Emitter On Voltage	V _{CE} = 1V, I _C = 100mA			0.9	V
Small Signal Characteristics						
C _{obo}	Output Capacitance	V _{CB} = 10V, I _E = 0			25	pF
Pulse Test: Pulse Width ≤ 300ms, Duty Cycle ≤ 2.0%						

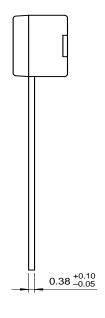
Thermal Characteristics $T_a=25$ °C unless otherwise noted

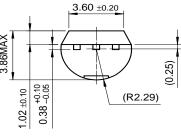
Symbol	Parameter	Max.	Units
P _D	Total Device Dissipation Derate above 25°C	625 5	mW mW/°C
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	83.3	°C/W
$R_{\theta JC}$	Thermal Resistance, Junction to Case	200	°C/W

Package Dimensions

TO-92







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